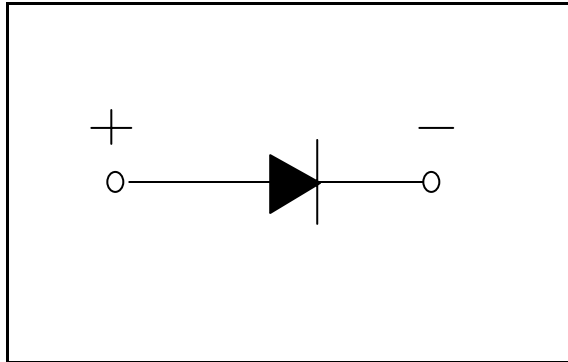


POW-R-BLOK™
Single Diode Isolated Module
2500 Amperes / Up to 2400 Volts**Ordering Information:**

Select the complete eight-digit module part number from the table below.

Example: PS412425 is a 2400 Volt, 2500A Average Dual Diode Isolated *POW-R-BLOK™* Module

Type	Voltage Volts (x100)	Current Amperes (x100)
PS41	18	25
	20	
	22	
	24	

Description:

Powerex Single Diode Modules are designed for use in applications requiring rectification and isolated packaging. The modules are isolated for easy mounting with other components on a common heatsink.

Features:

- Electrically Isolated Heatsinking
- Compression Bonded Elements
- Metal Baseplate
- Low Thermal Impedance for Improved Current Capability
- UL Recognized (E78240)

Benefits:

- No Additional Insulation Components Required
- Easy Installation
- No Clamping Components Required
- Reduce Engineering Time

Applications:

- Bridge Circuits
- AC & DC Motor Drives
- Battery Supplies
- Power Supplies
- Large IGBT Circuit Front Ends

Absolute Maximum Ratings

Characteristics	Conditions	Symbol		Units
Repetitive Peak Reverse Blocking Voltage		V_{RRM}	Up to 2400	V
Non-Repetitive Peak Blocking Voltage ($t < 5$ msec)		V_{RSM}	$V_{RRM} + 100V$	V
RMS Current Per Diode (180° Conduction)	180° Conduction, $T_C=90^\circ C$ 180° Conduction, $T_C=93^\circ C$ 180° Conduction, $T_C=99^\circ C$ 180° Conduction, $T_C=105^\circ C$	$I_{F(RMS)}$ $I_{F(RMS)}$ $I_{F(RMS)}$ $I_{F(RMS)}$	3925 3768 3454 3140	A A A A
Average Forward Current Per Diode (180° Conduction)	180° Conduction, $T_C=90^\circ C$ 180° Conduction, $T_C=93^\circ C$ 180° Conduction, $T_C=99^\circ C$ 180° Conduction, $T_C=105^\circ C$	$I_{F(AV)}$ $I_{F(AV)}$ $I_{F(AV)}$ $I_{F(AV)}$	2500 2400 2200 2000	A A A A
Peak One Cycle Surge Current, Non-Repetitive $T_j = 25C, V_r = 0$	60 Hz 50 Hz	I_{FSM} I_{FSM}	90,000 83,000	A A
Peak One Cycle Surge Current, Non-Repetitive $T_j = 25C, V_r = V_{rrm}$	60 Hz 50 Hz	I_{FSM} I_{FSM}	61,000 55,600	A A
Peak One Cycle Surge Current, Non-Repetitive $T_j = 125C, V_r = 0$	60 Hz 50 Hz	I_{FSM} I_{FSM}	79,600 72,600	A A
Peak One Cycle Surge Current, Non-Repetitive $T_j = 125C, V_r = V_{rrm}$	60 Hz 50 Hz	I_{FSM} I_{FSM}	53,000 48,400	A A
Peak Three Cycle Surge Current, Non-Repetitive	60 Hz, $T_j = 125C, V_r = V_{rrm}$	I_{FSM}	42,000	A
Peak Ten Cycle Surge Current, Non-Repetitive	60 Hz, $T_j = 125C, V_r = V_{rrm}$	I_{FSM}	33,500	A
I^2t for Fusing for One Cycle $T_j = 125C, V_r = V_{rrm}$	8.3 milliseconds 10 milliseconds	I^2t I^2t	11.7×10^6 11.7×10^6	$A^2 \text{ sec}$ $A^2 \text{ sec}$
Operating Temperature		T_J	-40 to +150	°C
Storage Temperature		T_{sig}	-40 to +150	°C
Max. Mounting Torque, M6 Mounting Screw			132 15	in. – Lb. Nm
Max. Mounting Torque, M10 Terminal Screw			106 12	in. – Lb. Nm
Module Weight, Typical			5.33 11.75	kg lb
V Isolation @ 25C		V_{rms}	3000	V

Information presented is based upon manufacturers testing and projected capabilities.
 This information is subject to change without notice.
 The manufacturer makes no claim as to suitability of use, reliability, capability,
 or future availability of this product.

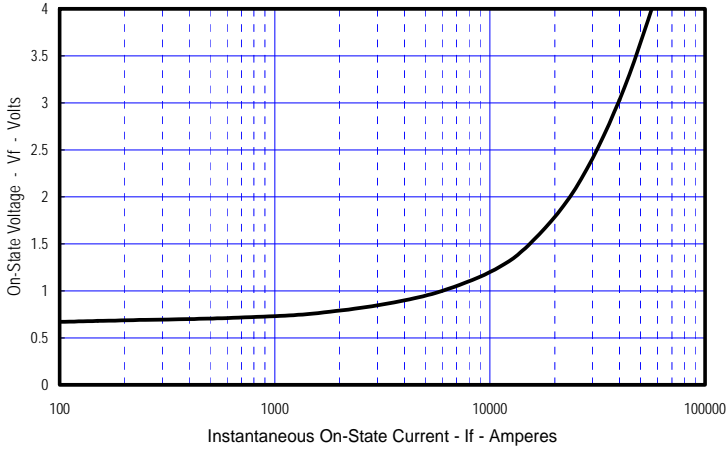
Electrical Characteristics, T_J=25°C unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Max.	Units
Repetitive Peak Reverse Leakage Current	I _{RPM}	Up to 2400V, T _J =125°C		200	mA
Peak On-State Voltage	V _{FM}	I _{FM} =3000A, T _J =150°C		1.00	V
Threshold Voltage, Low-level	V _{(TO)1}	T _J = 150°C, I = 15%I _{T(AV)} to πI _{T(AV)}		0.632	V
Slope Resistance, Low-level	r _{T1}			0.0598	mΩ
Threshold Voltage, High-level	V _{(TO)2}	T _J = 150°C, I = πI _{T(AV)} to I _{TSM}		0.550	V
Slope Resistance, High-level	r _{T2}			0.0625	mΩ
V _{FM} Coefficients, Full Range		T _J = 150°C, I = 50A to 10kA V _{FM} = A + B Ln I + C I + D Sqrt I	A = B = C = D =	0.040 0.116 7.56 E-05 -6354 E-03	
Typical Reverse Recovery Time	t _{rr}	T _J = 25°C, I _{FM} = 3000A. di/dt = 25 A/us, t _p = 190 us		22	us

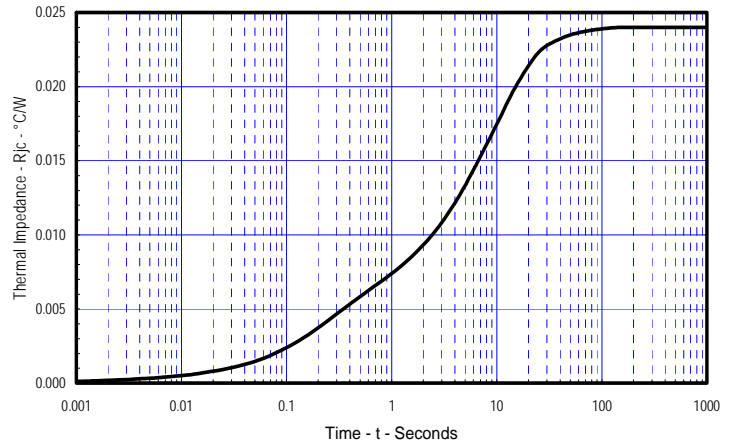
Thermal Characteristics

Characteristics	Symbol		Max.	Units
Thermal Resistance, Junction to Case	R _{ΘJ-C}	Per Module	0.024	°C/W
Thermal Impedance Coefficients	Z _{ΘJ-C}	Z _{ΘJ-C} = K ₁ (1-exp(-t/t ₁)) + K ₂ (1-exp(-t/t ₂)) + K ₃ (1-exp(-t/t ₃)) + K ₄ (1-exp(-t/t ₄))	K ₁ = 4.05 E-04 K ₂ = 5.19 E-03 K ₃ = 1.63 E-02 K ₄ = 2.13 E-03	t ₁ = 6.24 E-03 t ₂ = 2.46 E-01 t ₃ = 8.20 t ₄ = 35.3
Thermal Resistance, Case to Sink Lubricated	R _{ΘC-S}	Per Module	0.009	°C/W

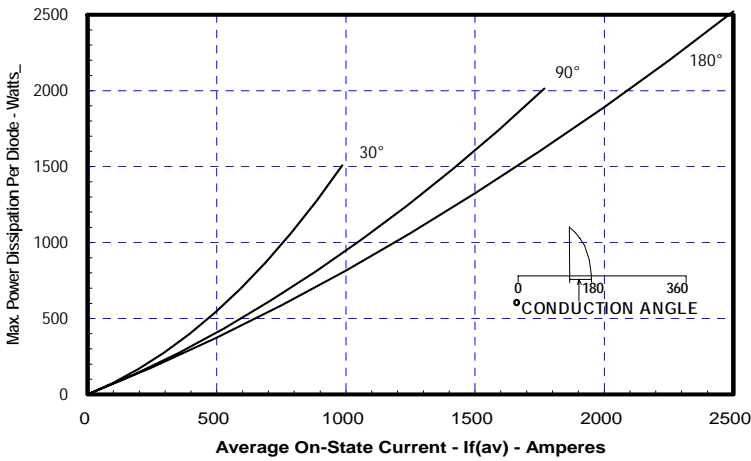
Typical On-State Forward Voltage Drop
($T_j = 150^\circ\text{C}$)



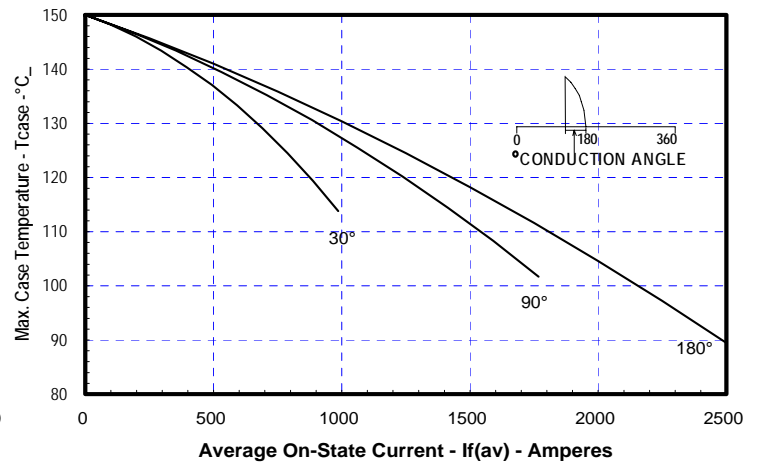
Maximum Transient Thermal Impedance
(Junction To Case)



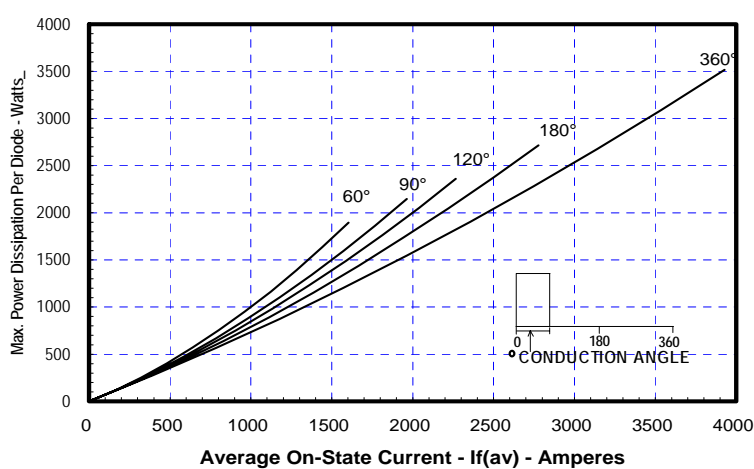
Maximum On-State Power Dissipation
(Sinusoidal Waveform)



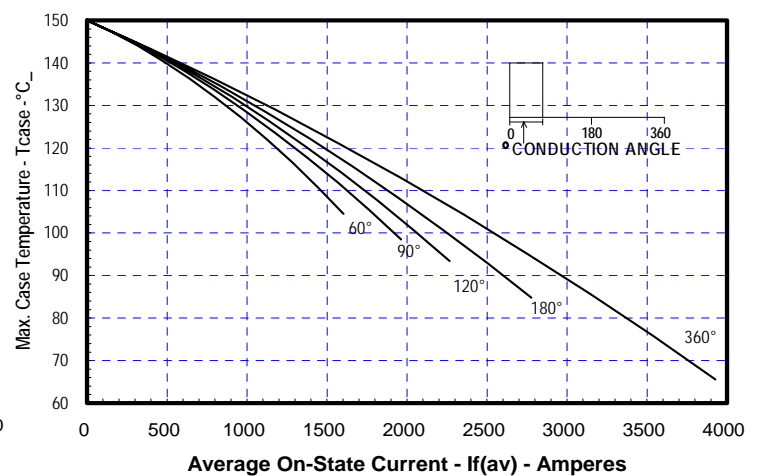
Maximum Allowable Case Temperature
(Sinusoidal Waveform)



Maximum On-State Power Dissipation
(Rectangular Waveform)



Maximum Allowable Case Temperature
(Rectangular Waveform)



POW-R-BLOK™
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DIM.	INCHES	MILLIMETERS
A	7.80	198.1
B	4.00	101.6
C	2.68	68.1
D	6.44	163.6
E	3.44	87.4
F	.28	7.1
G	7.31	185.7
H	7.00	177.8
M	.281	7.1
N	.45	11.4
P	.34	8.7
Q	5.93	150.6
R	.19	4.8
T	.48	12.2
U	2.28	58
V	2.54	64.5
W	4.93	125.2
X	3.81	96.8
Z	2.00	50.8
AA	1.00	25.4
BB	.50	12.7
CC	1.00	25.4
DD	.406	10.3
FF	.66	16.8

